

US1881

Hall Latch - High Sensitivity

Features and Benefits

- ☐ Wide operating voltage range from 3.5V to 24V
- ☐ High magnetic sensitivity Multi-purpose
- CMOS technology
- ☐ Chopper-stabilized amplifier stage
- ☐ Low current consumption
- ☐ Open drain output
- ☐ Thin SOT23 3L and flat TO-92 3L both RoHS Compliant packages

Application Examples

- ☐ Automotive, Consumer and Industrial
- Solid-state switch
- Brushless DC motor commutation
- Speed detection
- ☐ Linear position detection
- Angular position detection
- Proximity detection

Ordering Code

Product Code	Temperature Code	Package Code	Option Code	Packing Form Code
US1881	Ē	UA	AAA-000	ВŬ
US1881	K	UA	AAA-000	BU
US1881	L	UA	AAA-000	BU
US1881	E	SE	AAA-000	RE
US1881	K	SE	AAA-000	RE
US1881	L	SE	AAA-000	RE

Legend:

Temperature Code: L for Temperature Range -40 °C to 150 °C

E for Temperature Range -40 ℃ to 85 ℃ K for Temperature Range -40 ℃ to 125 ℃

Package Code: UA for TO-92(Flat), SE for TSOT

Option Code: xxx-000: Standard version Packing Form: RE for Reel, BU for Bulk

Ordering example: US1881KUA-AAA-000-BU

2 General Description

The Melexis US1881 is a Hall-effect latch designed in mixed signal CMOS technology.

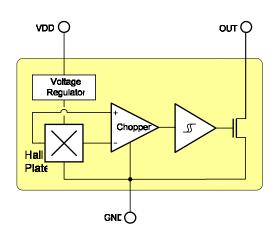
The device integrates a voltage regulator, Hall sensor with dynamic offset cancellation system, Schmitt trigger and an open-drain output driver, all in a single package.

Thanks to its wide operating voltage range and extended choice of temperature range, it is quite suitable for use in automotive, industrial and consumer applications.

The device is delivered in a Thin Small Outline Transistor (TSOT) for surface mount process and in a Plastic Single In Line (TO-92 flat) for throughhole mount.

Both 3-lead packages are RoHS compliant.

1 Functional Diagram







Hall Latch - High Sensitivity

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3 Glossary of Terms

MilliTesla (mT), Gauss Units of magnetic flux density:

1mT = 10 Gauss

RoHS Restriction of Hazardous Substances

TSOT Thin Small Outline Transistor (TSOT package) – also referred with the Melexis

package code "SE"

ESD Electro-Static Discharge BLDC Brush-Less Direct-Current

Operating Point (B_{OP}) Magnetic flux density applied on the branded side of the package which turns

the output driver ON $(V_{OUT} = V_{DSon})$

Release Point (B_{RP}) Magnetic flux density applied on the branded side of the package which turns

the output driver OFF ($V_{OUT} = high$)

4 Absolute Maximum Ratings

Parameter	Symbol	Value	Units
Supply Voltage	V_{DD}	28	V
Supply Current	I_{DD}	50	mA
Output Voltage	V_{OUT}	28	V
Output Current	Iout	50	mA
Storage Temperature Range	Ts	-50 to 150	°C
Maximum Junction Temperature	TJ	165	°C

Table 1: Absolute maximum ratings

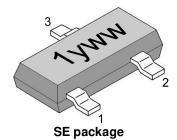
Exceeding the absolute maximum ratings may cause permanent damage. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

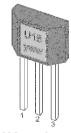
Operating Temperature Range	Symbol	Value	Units
Temperature Suffix "E"	T_{A}	-40 to 85	°C
Temperature Suffix "K"	T_A	-40 to 125	°C
Temperature Suffix "L"	T_A	-40 to 150	°C

5 Pin Definitions and Descriptions

SE Pin №	UA Pin №	Name	Type	Function
1	1	VDD	Supply	Supply Voltage pin
2	3	OUT	Output	Open Drain Output pin
3	2	GND	Ground	Ground pin

Table 2: Pin definitions and descriptions





UA package



6 General Electrical Specifications

DC Operating Parameters $T_A = 25^{\circ}C$, $V_{DD} = 3.5V$ to 24V (unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Supply Voltage	V_{DD}	Operating	3.5		24	V
Supply Current	I _{DD}	$B < B_{RP}$			5	mA
Output Saturation Voltage	V _{DSon}	$I_{OUT} = 20 \text{mA}, B > B_{OP}$			0.5	V
Output Leakage Current	Ioff	$B < B_{RP}, V_{OUT} = 24V$		0.3	10	μA
Output Rise Time	$t_{\rm r}$	$R_L = 1k\Omega$, $C_L = 20pF$		0.25		μs
Output Fall Time	t_{f}	$R_L = 1k\Omega$, $C_L = 20pF$		0.25		μs
Maximum Switching Frequency	Fsw			10		KHz
Package Thermal Resistance	R _{TH}	Single layer (1S) Jedec board		301		°C/W

Table 3: Electrical specifications

7 Magnetic Specifications

DC Operating Parameters $V_{DD} = 3.5V$ to 24V (unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Operating Point	Вор		0.5		9.5	mT
Release Point	Brp	E spec., $T_A = 85^{\circ}C$	-9.5		-0.5	mT
Hysteresis	BHYST		7		12	mT
Operating Point	Вор		0.5		9.5	mT
Release Point	B _{RP}	K spec., $T_A = 125^{\circ}C$	-9.5		-0.5	mT
Hysteresis	BHYST		7		12	mT
Operating Point	Bop		0.5		9.5	mT
Release Point	Brp	L spec., $T_A = 150^{\circ}C$	-9.5		-0.5	mT
Hysteresis	B _{HYST}		6		12.5	mT

Table 4: Magnetic specifications

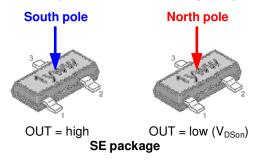
Note 1: For typical values, please refer to the performance graphs in section 11

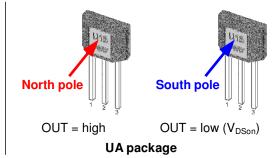
8 Output Behaviour versus Magnetic Pole

DC Operating Parameters $T_A = -40$ °C to 150 °C, $V_{DD} = 3.5 V$ to 24 V (unless otherwise specified)

Parameter	Test Conditions (SE)	OUT (SE)	Test Conditions (UA)	OUT (UA)
South pole	B < B _{RP}	High	$B > B_{OP}$	Low
North pole	B > B _{OP}	Low	B < B _{RP}	High

Table 5: Output behaviour versus magnetic pole







9 Detailed General Description

Based on mixed signal CMOS technology, Melexis US1881 is a Hall-effect device with high magnetic sensitivity. This multi-purpose latch suits most of the application requirements.

The chopper-stabilized amplifier uses switched capacitor technique to suppress the offset generally observed with Hall sensors and amplifiers. The CMOS technology makes this advanced technique possible and contributes to smaller chip size and lower current consumption than bipolar technology. The small chip size is also an important factor to minimize the effect of physical stress.

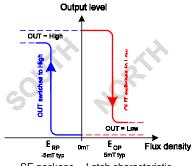
This combination results in more stable magnetic characteristics and enables faster and more precise design.

The wide operating voltage from 3.5V to 24V, low current consumption and large choice of operating temperature range according to "L", "K" and "E" specification make this device suitable for automotive, industrial and consumer applications.

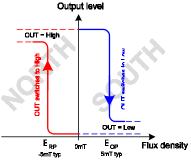
The output signal is open-drain type. Such output allows simple connectivity with TTL or CMOS logic by using a pull-up resistor tied between a pull-up voltage and the device output.

10 Unique Features

The US1881 exhibits latch magnetic switching characteristics. Therefore, it requires both south and north poles to operate properly.



SE package - Latch characteristic



UA package - Latch characteristic

The device behaves as a latch with symmetric operating and release switching points ($B_{OP}=|B_{RP}|$). This means magnetic fields with equivalent strength and opposite direction drive the output high and low.

Removing the magnetic field $(B\rightarrow 0)$ keeps the output in its previous state. This latching property defines the device as a magnetic memory.

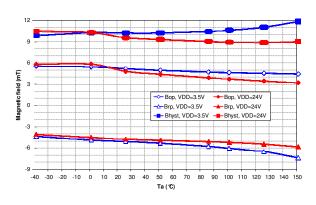
A magnetic hysteresis B_{HYST} keeps B_{OP} and B_{RP} separated by a minimal value. This hysteresis prevents output oscillation near the switching point.



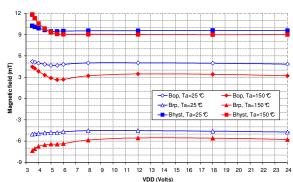


11 Performance Graphs

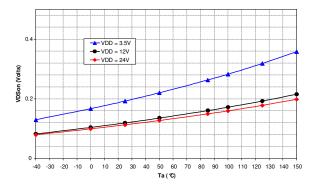
11.1 Magnetic parameters vs. T_A



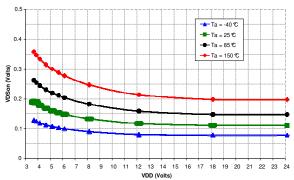
11.2 Magnetic parameters vs. V_{DD}



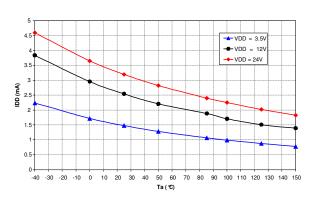
11.3 V_{DSon} vs. T_A



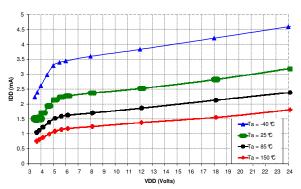
11.4 V_{DSon} vs. V_{DD}



11.5 I_{DD} vs. T_A



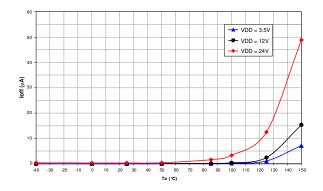
11.6 I_{DD} vs. V_{DD}



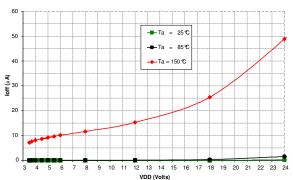




11.7 loff vs. TA



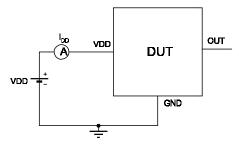
11.8 I_{OFF} vs. V_{DD}



12 Test Conditions

Note: DUT = Device Under Test

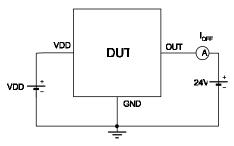
12.1 Supply Current



Note 1 - The supply current $_{\rm DD}$ represents the static supply current. OUT is left open during measurement.

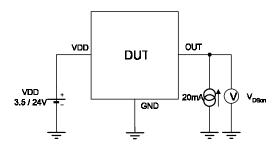
Note 2 - The device is put under magnetic field with B<B_{RP}.

12.3 Output Leakage Current



Note 1 - The device is put under magnetic field with B<B_{RP}

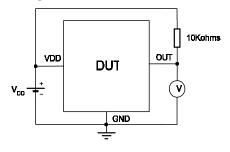
12.2 Output Saturation Voltage



Note 1 - The output saturation voltage V_{DSon} is measured at V_{DD} = 3.5V and V_{DD} = 24V

Note 2 - The device is put under magnetic field with B>B_{OP}.

12.4 Magnetic Thresholds



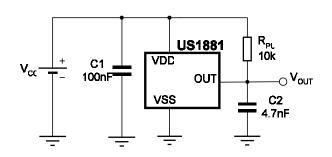
Note 1 - B_{QP} is determined by putting the device under magnetic field swept from E_{RPmin} up to B_{QPmax} until the output is switched on.

Note 2 - $B_{_{RP}}$ is determined by putting the device under magnetic field swept from $E_{_{QP_{100K}}}$ down to $B_{_{RPmin}}$ until the output is switched off.

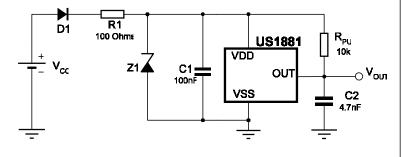


13 Application Information

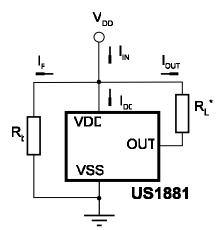
13.1 Typical Three-Wire Application Circuit



13.3 Automotive and Harsh, Noisy Environments **Three-Wire Circuit**



13.2 Two-Wire Circuit



Note:

With this circuit, precise ON and OFF currents can be detected using only two connecting wires.

The resistors RL and Rb can be used to bias the input current. Refer to the part specifications for limiting values.

$$\begin{split} B_{RP}: \quad I_{OFF} &= I_R \ + I_{DD} = V_{DD}/R_b + I_{DD} \\ B_{OP}: \quad I_{ON} &= I_{OFF} + I_{OUT} = I_{OFF} + V_{DD}/R_L \end{split}$$

14 Application Comments

For proper operation, a 100nF bypass capacitor should be placed as close as possible to the device between the V_{DD} and ground pin.

For reverse voltage protection, it is recommended to connect a resistor or a diode in series with the V_{DD} pin. When using a resistor, three points are important:

- the resistor has to limit the reverse current to 50mA maximum (V_{CC} / $R1 \le 50mA$)
- the resulting device supply voltage V_{DD} has to be higher than V_{DD} min ($V_{DD} = V_{CC} R1.I_{DD}$) the resistor has to withstand the power dissipated in reverse voltage condition ($P_D = V_{CC}^2/R1$)

When using a diode, a reverse current cannot flow and the voltage drop is almost constant (≈0.7V).

Therefore, a $100\Omega/0.25W$ resistor for 5V application and a diode for higher supply voltage are recommended. Both solutions provide the required reverse voltage protection.

When a weak power supply is used or when the device is intended to be used in noisy environment, it is recommended that figure 13.3 from the Application Information section is used.

The low-pass filter formed by R1 and C1 and the zener diode Z1 bypass the disturbances or voltage spikes occurring on the device supply voltage V_{DD}. The diode D1 provides additional reverse voltage protection.



15 Standard information regarding manufacturability of Melexis products with different soldering processes

Our products are classified and qualified regarding soldering technology, solderability and moisture sensitivity level according to following test methods:

Reflow Soldering SMD's (Surface Mount Devices)

- IPC/JEDEC J-STD-020
 Moisture/Reflow Sensitivity Classification for Nonhermetic Solid State Surface Mount Devices (classification reflow profiles according to table 5-2)
- EIA/JEDEC JESD22-A113
 Preconditioning of Nonhermetic Surface Mount Devices Prior to Reliability Testing (reflow profiles according to table 2)

Wave Soldering SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

- EN60749-20
 Resistance of plastic- encapsulated SMD's to combined effect of moisture and soldering heat
- EIA/JEDEC JESD22-B106 and EN60749-15
 Resistance to soldering temperature for through-hole mounted devices

Iron Soldering THD's (Through Hole Devices)

EN60749-15
 Resistance to soldering temperature for through-hole mounted devices

Solderability SMD's (Surface Mount Devices) and THD's (Through Hole Devices)

 EIA/JEDEC JESD22-B102 and EN60749-21 Solderability

For all soldering technologies deviating from above mentioned standard conditions (regarding peak temperature, temperature gradient, temperature profile etc) additional classification and qualification tests have to be agreed upon with Melexis.

The application of Wave Soldering for SMD's is allowed only after consulting Melexis regarding assurance of adhesive strength between device and board.

Melexis is contributing to global environmental conservation by promoting **lead free** solutions. For more information on qualifications of **RoHS** compliant products (RoHS = European directive on the Restriction Of the use of certain Hazardous Substances) please visit the quality page on our website: http://www.melexis.com/quality.aspx

16 ESD Precautions

Electronic semiconductor products are sensitive to Electro Static Discharge (ESD).

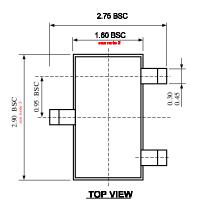
Always observe Electro Static Discharge control procedures whenever handling semiconductor products.

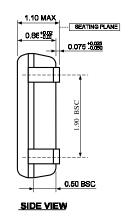


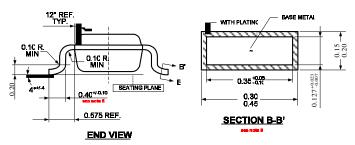
Hall Latch - High Sensitivity

17 Package Information

17.1 SE Package (TSOT-3L)







Notes:

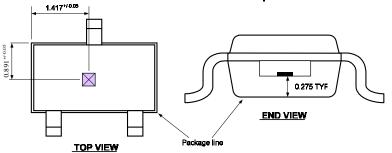
- 1. All dimensions are in millimeters
- Cutermost plastic extreme width does not include mold flash or protrusions. Mold flash and protrusions shall not exceed 0.15mm per side.
- Outsimost plastic extreme length does not include mold flash or protrusions. Mold flash and protrusions shall not exceed 0.25mm per side.
- The lead width dimension does not include dambar protrusion
 Allowable dambar protrusion shall be 0.07mm total in excess
 of the lead width dimension at maximum material condition.
- 5. Dimension is the length of terminal for soldering to a substrate.
- 6. Dimension on SECTION B-B' are apply to the flat section of the lead between 0.08mm and 0.15mm from the lead tip.
- Formed lead shall be planar with respect to one another with 0.076mm at seating plane.

Marking:

Top side : 1yww

1 = part number (US1881) y = last digit of yea ww = calendar week

Hall plate location



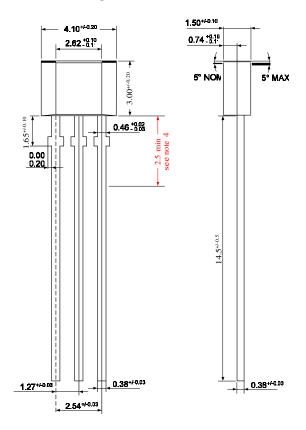
Notes

1. All dimensions are in millimeters





17.2 UA Package (TO-92 flat)



Notes:

- 1. All dimensions are in millimeters
- 2. Package dimension exclusive molding flash
- The end flash shall not exceed 0.127 mm on each side.
- To preserve reliability, it is recommended to have total lead length equal to 2.5mm minimum, measured from the package line.

Marking:

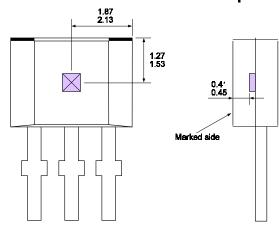
1st Line: U18 - Part number (US1881)

2nd Line: yww

y - last digit of year ww - calendar week



Hall plate location



Notes:

1. All dimensions are in millimeters

US1881 Hall Latch - High Sensitivity

18 Disclaimer

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